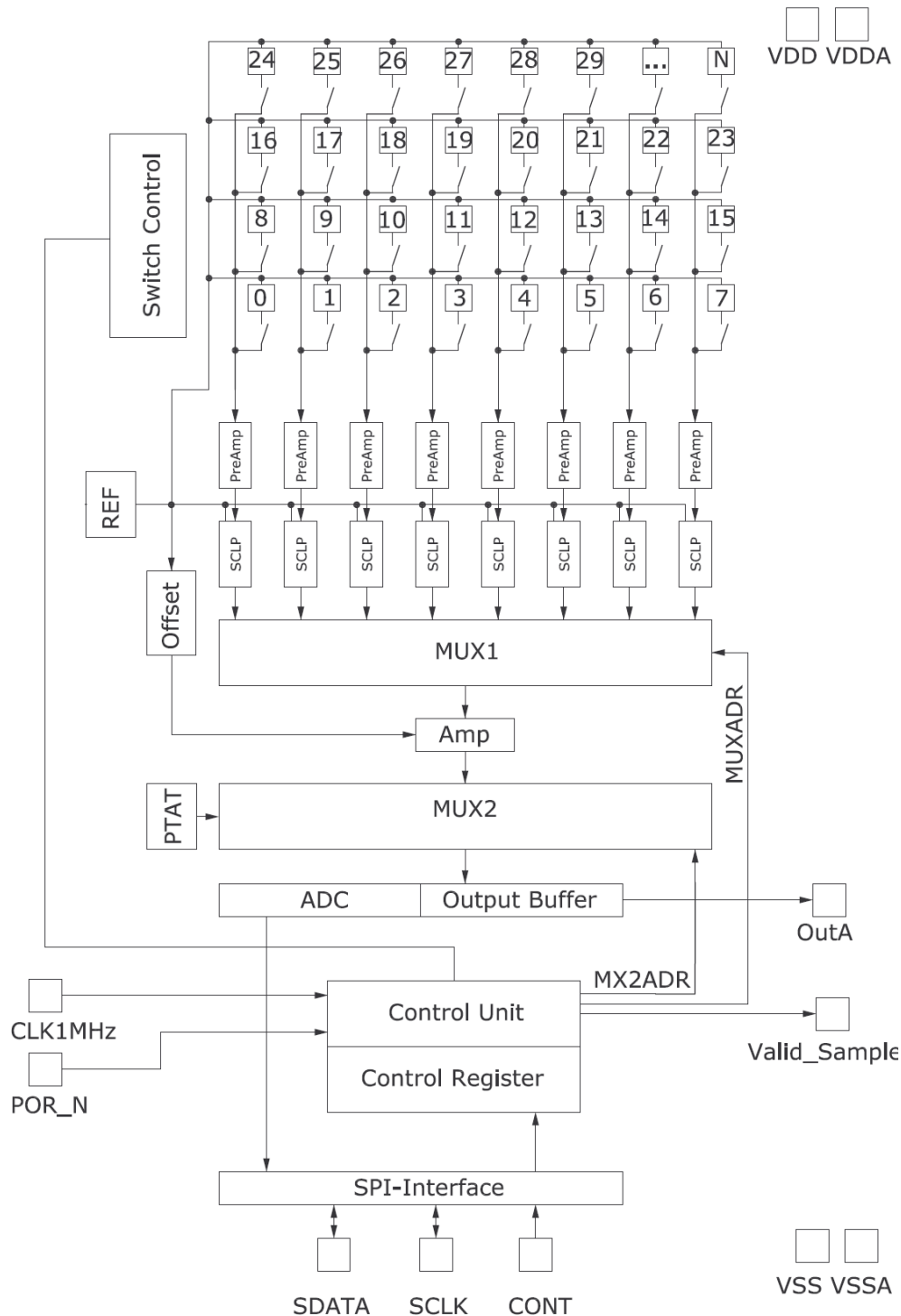
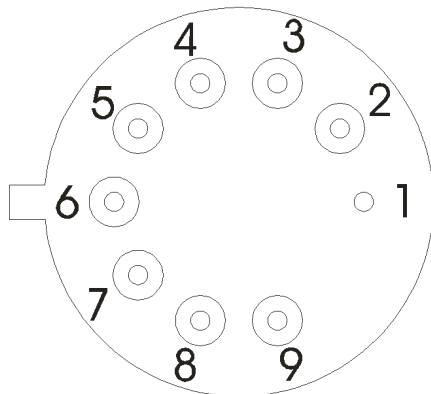


Principal Schematic for HTPA8x8:



Pin Assignment in TO39 – Bottom View:



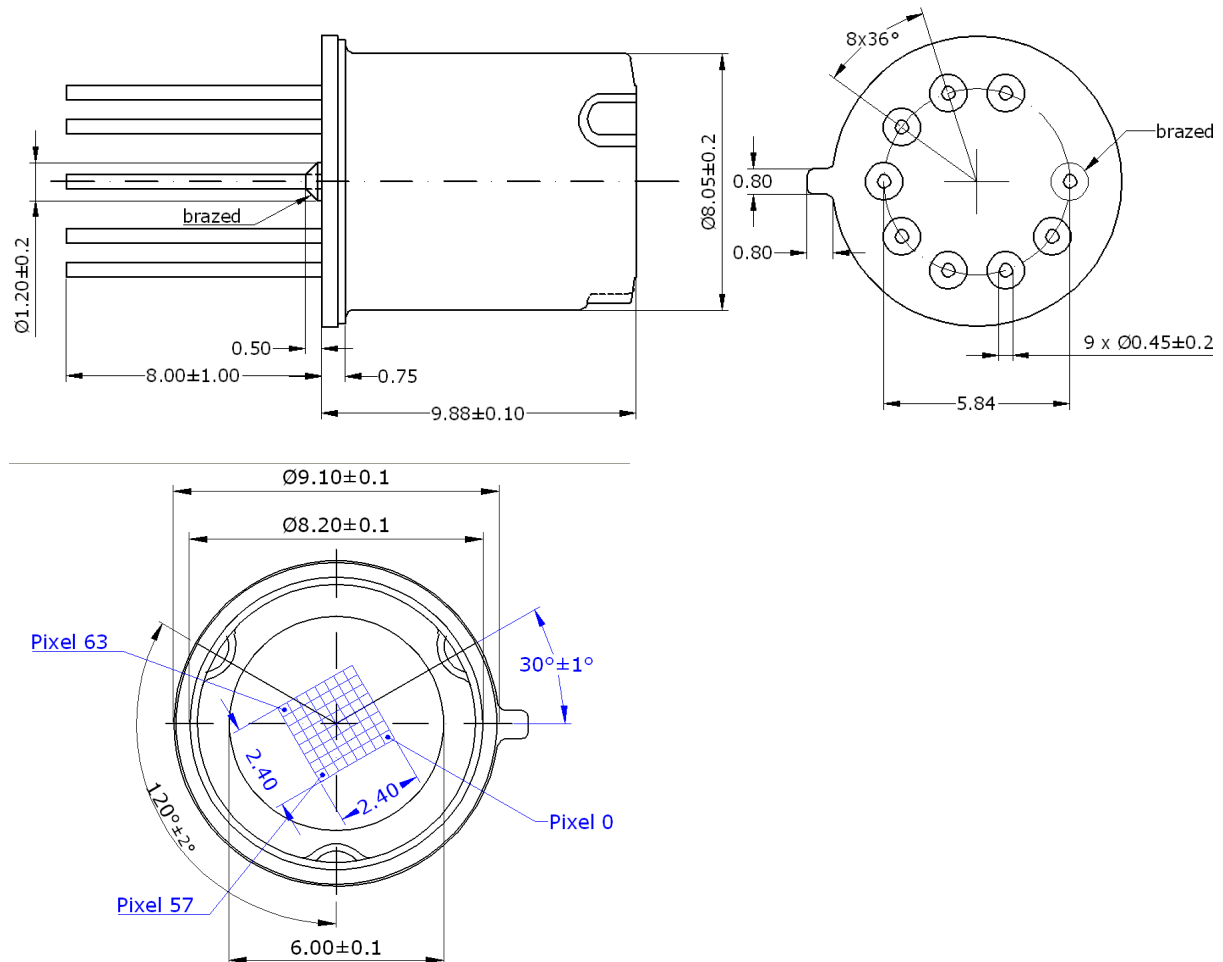
Connect all reference voltages via 100 nF capacitors to VSS.

Pin Assignment 8x8			
Pin	Name	Description	Type
1	VSS	Negative power supply voltage	Power
2	VDD	Positive power supply voltage	Power
3	OUT_A	Analog Output	Analog Output
4	VCM_C	Common mode voltage	Reference Voltage*
5	DATA_IO	Data input/output for SPI	Digital Input/Output
6	CONT	Control Pin for SPI	Digital Input
7	SCLK_IO	Clock input/output for SPI	Digital Input/Output
8	VSAM	Valid sample	Digital Output
9	CLK_1MHZ	Master clock	Digital Input

*) Connect via 100 nF to VSS

Outer Dimensions:

HTPA8x8L7 in TO39 (single Silicon Lens, focal length 7 mm):



Internal Register Map 8x8:

Num	Name	Function	Notes
0	R	Reset	1: Mux-Pixel-Counter on reset
'(2:1)	OPCTL(1:0)	Selection of operating point Reference choice at SCLP	00: VrefN 01: CM 10: VrefP
'(9:3)	MA(6:0)	Adress for static pixel selection	
10	AIM	Adress Increment Mode	0: adress = MA 1: auto adress inrement
11	AMP	Amplification	1: high amplification
14	SDL	SCLK Divider Low	different clock dividers for operating SCLK SCLK = MCLK / 2, 4, 8
15	SDH	SCLK Divider High	

Characteristics:

Common Specifications:

- Number of Thermocouples 80
- Technology n-poly/p-poly Si
- Element Resistance approx. 80 kOhms
- Sensitivity approx. 75 V/W without optics and filter
- Thermal Pixeltime constant <4 ms
- MUX preamplifier noise approx. 30 nV/ $\sqrt{\text{Hz}}$
- Pixel + amplifier noise approx. 50 nV/ $\sqrt{\text{Hz}}$
- Digital Interface SPI
- Analog Output Yes
- 2 point selectable Gains 2640x / 7920 x
- Pitch 300 μm
- Absorber size 220 μm
- Max. Framerate 100 Hz
(without Averaging)
- 4 internal Amps + MUX
- 64 sensitive elements

Optical characteristics:

- Focal length: 7mm ("L" equals the focal length of the lens)
- F-Number: 1.2
- Field of view: 19.5°
- lens coating: AR-Coating; average reflectance per surface
< 3% for 8 μm < λ < 11,5 μm
Environment acc. for MIL-C-48497

Electric Specifications:

Absolute Maximum Ratings:

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Supply Voltage	V _{CC}		-0.5		6	V
Voltage at All inputs and outputs	V _{IO}		-0.5		V _{CC} +0.5	V
Storage Temperature	T _{STG}		-30		125	Deg. C

Operating Conditions:

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Supply Voltage	V _{CC}		4.5		5.5	V
Operation Temperature	T _A		0		85	Deg. C
ESD-Protection		Human body model	1.5			kV
		100pF + 1k50hm				

Electrical Characteristics

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
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Digital Input

Frequency of MCLK	MCLK		100k	1M	TBD	Hz
Input voltage high	V _{IH}		V _{dd} -1.2			V
Input voltage low	V _{IL}				1.2	V
Operating Frequency	f _{OP}	CLK_1MHz	100k	1M	TBD	Hz

PTAT

Temperature range			0		85	Deg. C
PTAT value@ -20°C				TBD		V
PTAT value@100°C				TBD		V

Signal Processing

First amplifier stage gain	G0		TBD	880	TBD	V/V
Second amplifier stage gain	G1	AMPL=0	TBD	3	TBD	V/V
Second amplifier stage gain	G1	AMPL=1	TBD	9	TBD	V/V
Analog path Output ripple	V _{PPSENS}	CLK_1MHz	65	91	120	mV
Temp. coefficient Thermopile path output voltage	TCO _{OUTA}		TBD	-	TBD	mV/K

VoltageReference

VREF_1225	V _{REF}	V _{CC} =5V, T _{amb} =25°C	1.2	1.225	1.25	V
Temp. coeff. of V _{REF}	TC _{REF}		35	100	156	ppm/K

Electrical Characteristics (continued)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
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Analog Output

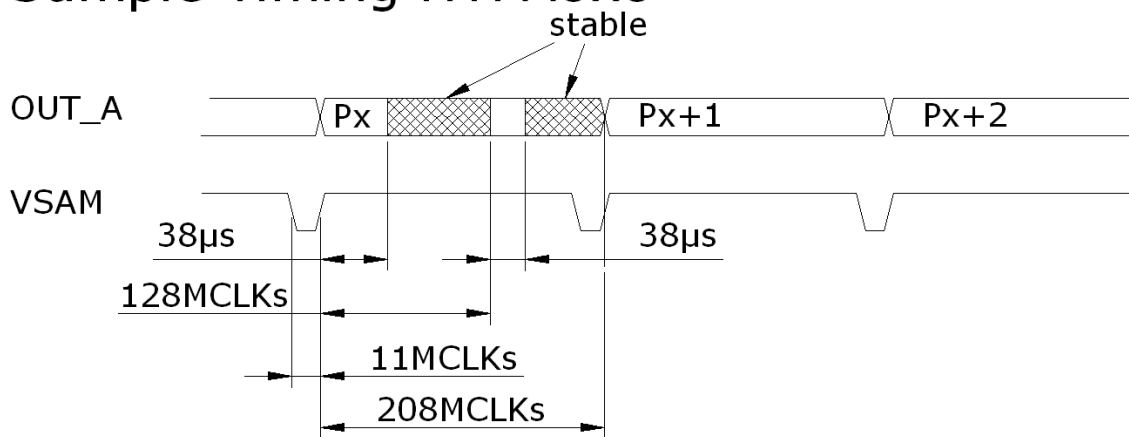
Output voltage swing	V_{OUTA}	load 10kOhm	0.5		$V_{CC}-0.8$	V
Power supply rejection ratio	P_{SRR}	AMPL=0 VDD<5V	-16			dB
Output current limit	I_{OUTA}	OUT_A	0.15			mA

General Parameters

Overall current consumption	I_{DD}	CLK_1MHz=1MHz 25° C	4.5	4.8	5.3	mA
Start up time	T_{POR}	Power On to first VSAM transition			805	cycles

Timings HTPA8x8:

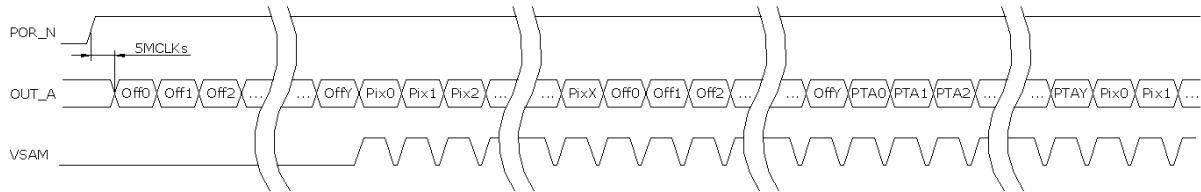
Sample Timing HTPA8x8



For the HTPA 8x8 every analogous voltage has 2 stable domains, as shown above.

Serial Transmission:

HTPA8x8 Serial Transmission of analogue data



Off0...OffY Electric offset of amplifier 0 to amplifier Y
Pix0...PixX Amplified pixel voltage of Pixel0 to PixelX
PTA0...PTAY PTAT-Signal

Constants for array types:

Type 8x8:

Y=3

X=63

The numeration of the pixels is in all cases line by line.

SPI Communication:

Data sampled at rising edge of SCLK, MSB first.

In case of ASIC as master device the frequency of the SCLK_IO is equal to the frequency of MCLK/2.

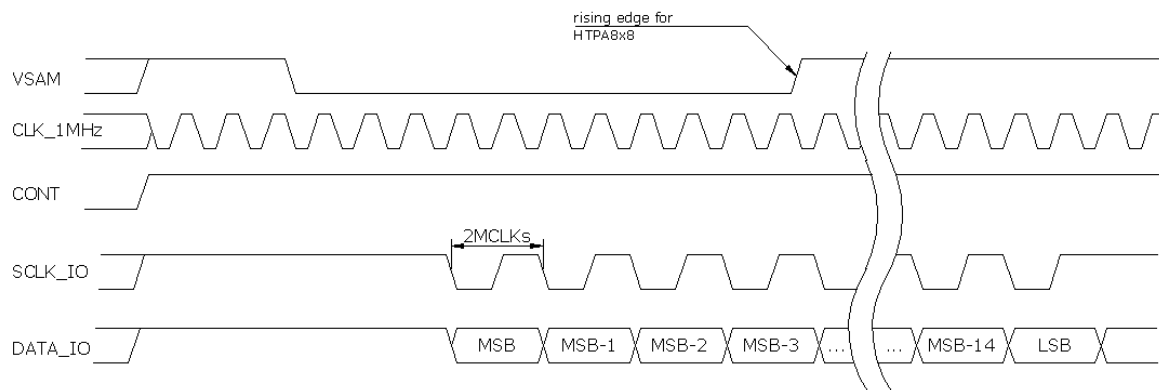
HTPA8x8:

The four MSB's signify the row address of the current pixel, the other bits describe the ADC-result. The ADC result has a large offset and therefore is not accurate. However, it might be used for movement detection or other applications, which not require absolute temperature measurements.

The output drivers for SCLK_IO and DATA_IO are enabled by CONT.

If CONT is low the data can be written serially from external controller through DATA_IO. In that case the external controller has to wait a minimum delay time, until SCLK_IO and DATA_IO output drivers are disabled. After programming, the positive slope of CONT stores the contents, when the number of SCLK-pulses is equal 16. While the output driver of the ASIC is disabled a weak pull up ensures that the SCLK_IO pin is at high level. To execute a reset command, the μ C has to write a logical "1" to the R-Bit in to configuration and afterwards a "0" into the R-bit, which requires two write cycles in this special case.

Serial Read from ASIC



Serial Write to ASIC

